NSN 5961-00-045-8627

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-045-8627 **Inclosure Material:** Metal **Overall Length:** 0.206 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.320 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -60.0 collector to base voltage/static/emitter open all transistor and -35.0 collector to emitter voltage/static/base open all transistor **Power Rating Per Characteristic:** 1.6 watts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 180.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No